



SANYO Semiconductors

DATA SHEET

MCH6544

 — NPN Epitaxial Planar Silicon Transistor
Inverter Circuit / Driver Applications

Applications

- Relay drivers, lamp drivers, motor drivers.

Features

- Composite type with an NPN transistor contained in one package facilitating high-density mounting.
- Ultrasmall package facilitates miniaturization in end products.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		60	V
Collector-to-Emitter Voltage	V _{CEO}		50	V
Emitter-to-Base Voltage	V _{EBO}		5	V
Collector Current	I _C		500	mA
Collector Current (Pulse)	I _{CP}		1.5	A
Collector Dissipation	P _C	When mounted on ceramic substrate (600mm ² ×0.8mm) 1unit	0.5	W
Total Power Dissipation	P _T	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.55	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CB0}	V _{CB} =40V, I _E =0A			100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0A			100	nA
DC Current Gain	h _{FE}	V _{CE} =2V, I _C =10mA	300		800	
Gain-Bandwidth Product	f _T	V _{CE} =10V, I _C =50mA		500		MHz
Output Capacitance	C _{ob}	V _{CB} =10V, f=1MHz		2.8		pF

Marking : ES

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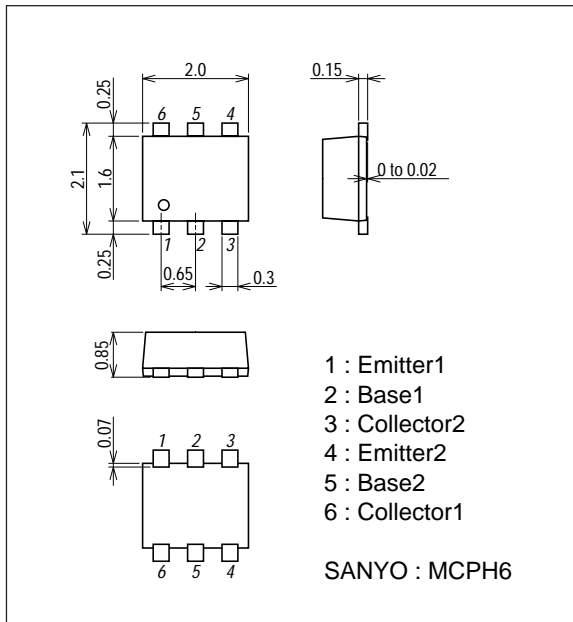
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA, I_B=10mA$		50	100	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=100mA, I_B=10mA$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}	See specified Test Circuit.		340		ns
Fall Time	t_f	See specified Test Circuit.		55		ns

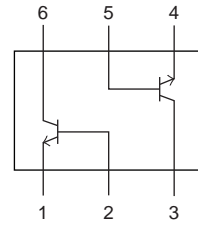
Package Dimensions

unit : mm (typ)

7022A-011



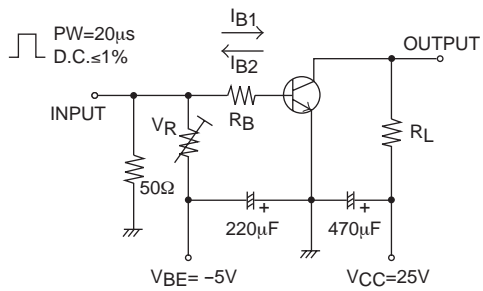
Electrical Connection



- 1 : Emitter1
- 2 : Base1
- 3 : Collector2
- 4 : Emitter2
- 5 : Base2
- 6 : Collector1

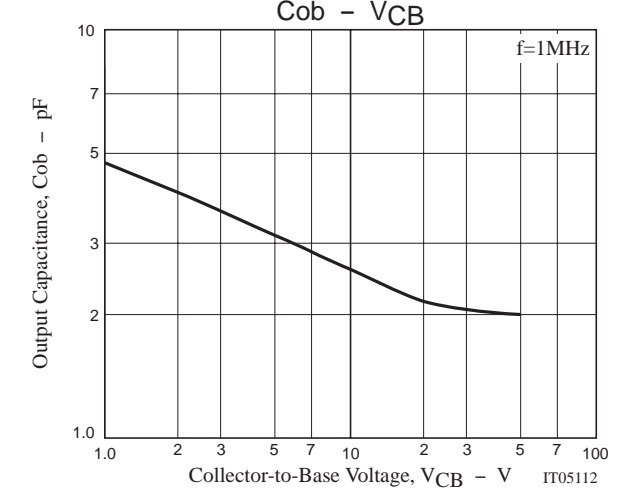
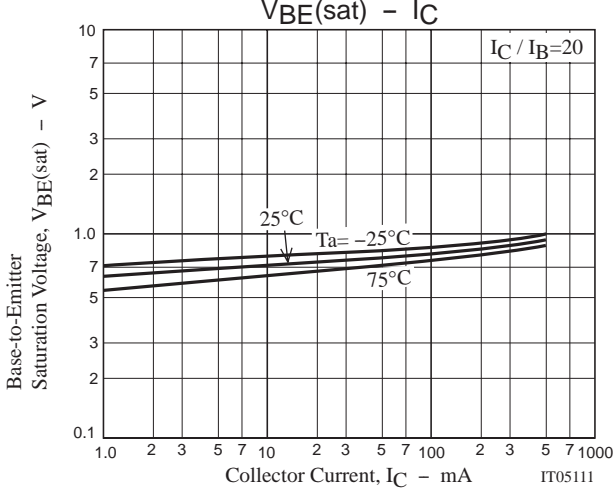
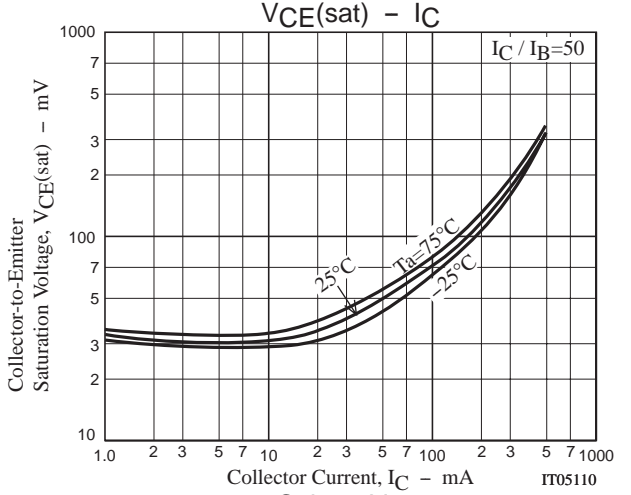
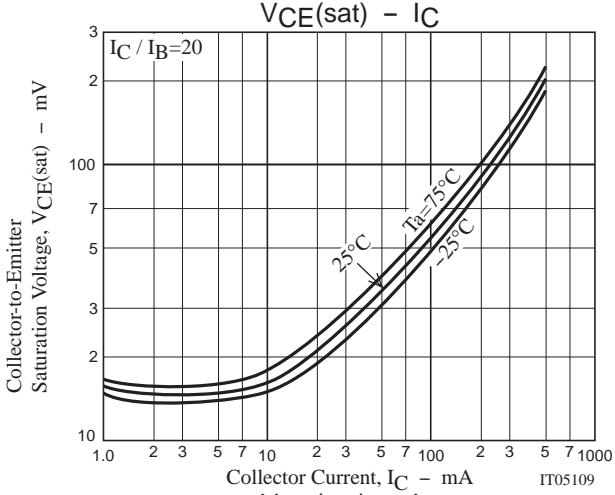
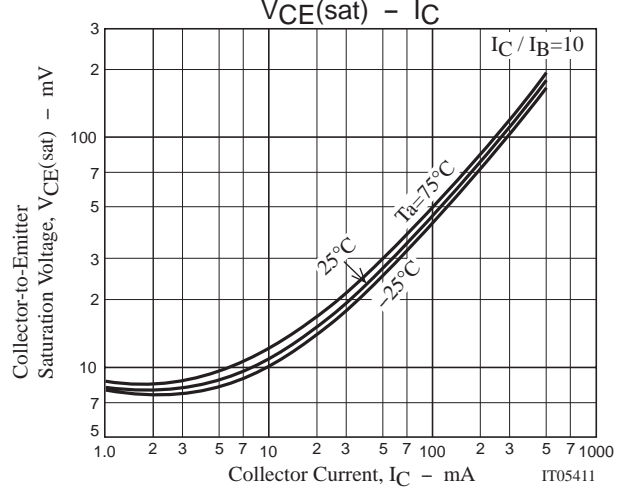
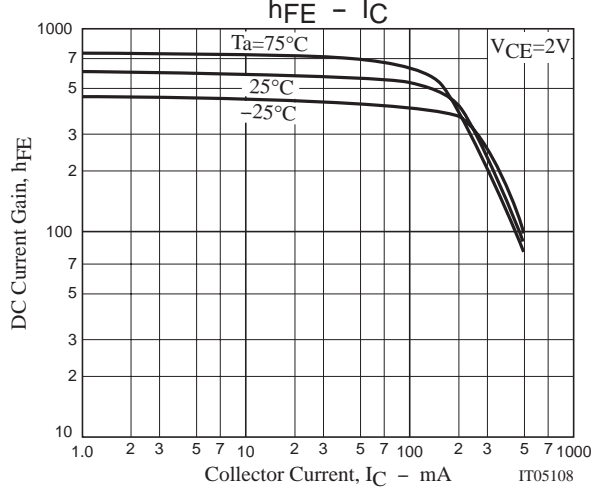
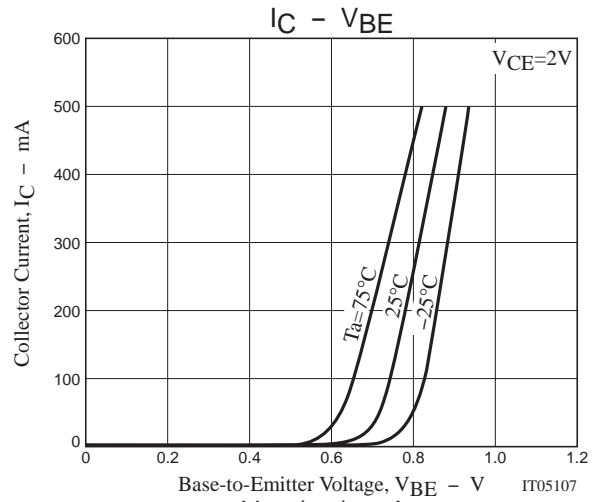
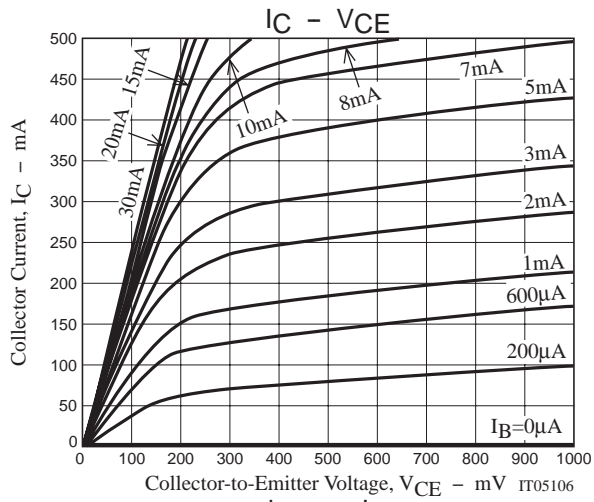
Top view

Switching Time Test Circuit

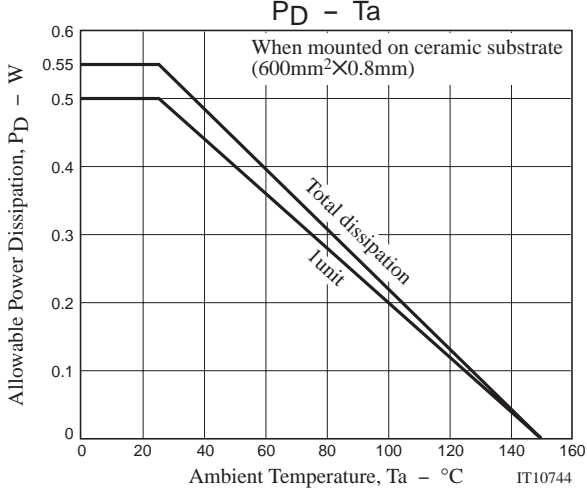
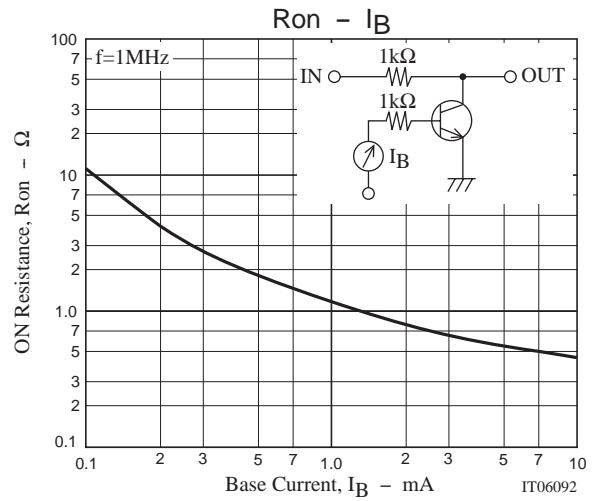
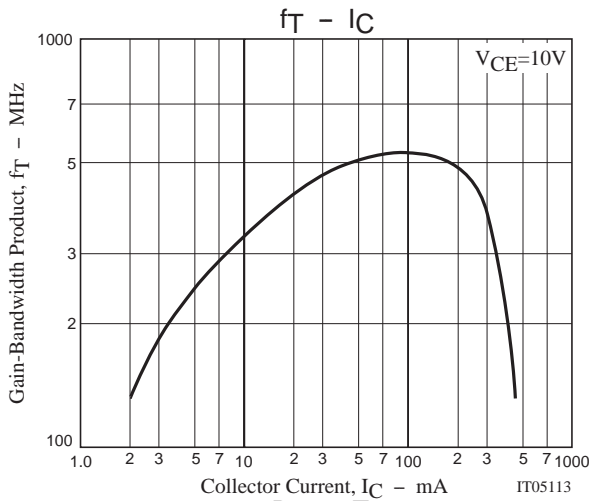


$$I_C=20I_{B1} = -20I_{B2}=200mA$$

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